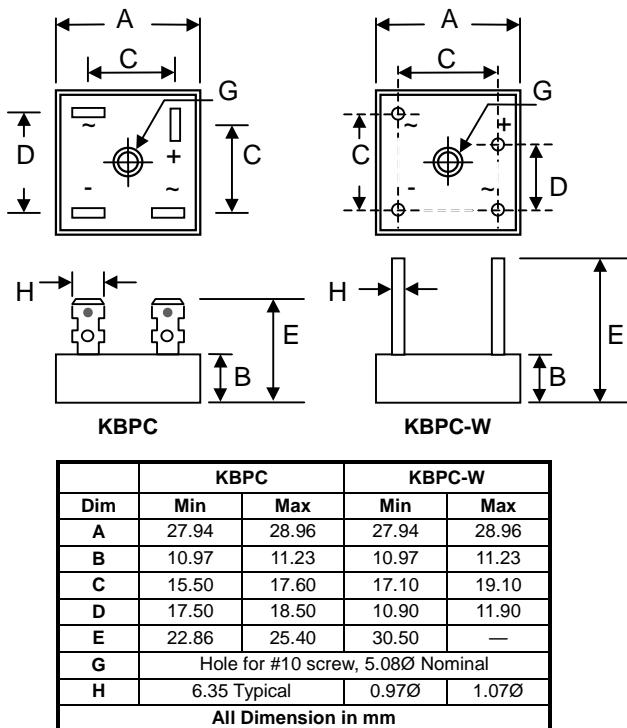


## Features

- Diffused Junction
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- Electrically Isolated Metal Case for Maximum Heat Dissipation
- Case to Terminal Isolation Voltage 2500V

## Mechanical Data

- Case: KBPC (Metal Case with Faston Lugs) or KBPC-W (Metal Case with Wire Leads)
- Terminals: Plated Faston Lugs or Wire Leads, Add "W" Suffix to Indicate Wire Leads
- Polarity: As Marked on Case
- Mounting: Through Hole with #10 Screw
- Mounting Torque: 23 cm-kg (20 in-lbs) Max.
- Weight: 30 grams (KBPC); 28 grams (KBPC-W)
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version**



## Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	KBPC50										Unit
		00	01	02	04	06	08	10	12	14	16	
Peak Repetitive Reverse Voltage	VR <sub>RM</sub>											
Working Peak Reverse Voltage	VR <sub>WM</sub>	50	100	200	400	600	800	1000	1200	1400	1600	V
DC Blocking Voltage	V <sub>R</sub>											
RMS Reverse Voltage	V <sub>R</sub> (RMS)	35	70	140	280	420	560	700	840	980	1120	V
Average Rectified Output Current @ $T_A = 60^\circ\text{C}$	I <sub>O</sub>	50										A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	450										A
Forward Voltage per leg @ $I_F = 25\text{A}$	V <sub>FM</sub>	1.2										V
Peak Reverse Current @ $T_c = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_c = 125^\circ\text{C}$	I <sub>RM</sub>	10 1.0										µA mA
I <sup>2</sup> t Rating for Fusing (t < 8.3ms)	I <sup>2</sup> t	800										A <sup>2</sup> s
Typical Junction Capacitance (Note 1)	C <sub>J</sub>	300										pF
Typical Thermal Resistance per leg (Note 2)	R <sub>θJC</sub>	1.6										°C/W
RMS Isolation Voltage from Case to Leads	V <sub>ISO</sub>	2500										V
Operating and Storage Temperature Range	T <sub>j</sub> , T <sub>STG</sub>	-65 to +150										°C

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance junction to case, mounted on heatsink.

